SIEMENS

Data sheet 3RF2330-1BA04



Solid-state contactor 1-phase 3RF2 AC 15 / 15 A / 40 $^{\circ}\text{C}$ 48-460 V / 24 V DC screw terminal Instantaneous switching

| product brand name | SIRIUS |
|---|--|
| product designation | solid-state contactor |
| design of the product | single-phase |
| product type designation | 3RF23 |
| manufacturer's article number | |
| _1 of the accessories that can be ordered | 3RF2900-3PA88 |
| _2 of the accessories that can be ordered | 3RF2950-0HA16 |
| _3 of the accessories that can be ordered | 3RF2900-0EA18 |
| _4 of the accessories that can be ordered | 3RF2950-0GA16 |
| _5 of the accessories that can be ordered | 3RF2920-0FA08 |
| product designation | |
| _1 of the accessories that can be ordered | terminal cover |
| _2 of the accessories that can be ordered | power regulator |
| _3 of the accessories that can be ordered | converter |
| _4 of the accessories that can be ordered | load monitoring |
| _5 of the accessories that can be ordered | load monitoring, basis |
| General technical data | |
| product function | instantaneous switching |
| power loss [W] for rated value of the current | |
| at AC in hot operating state | 33 W |
| at AC in hot operating state per pole | 33 W |
| without load current share typical | 0.4 W |
| insulation voltage rated value | 600 V |
| degree of pollution | 3 |
| type of voltage | |
| of the operating voltage | AC |
| of the control supply voltage | DC |
| surge voltage resistance of main circuit rated value | 6 kV |
| protection class IP | IP20 |
| protection class IP on the front according to IEC 60529 | IP20 |
| shock resistance according to IEC 60068-2-27 | 15g / 11 ms |
| vibration resistance according to IEC 60068-2-6 | 2g |
| reference code according to IEC 81346-2 | Q |
| Substance Prohibitance (Date) | 05/28/2009 |
| SVHC substance name | Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8 Dibutylbis(pentane-2,4-dionato-O,O')tin - 22673-19-4 |
| Weight | 0.31 kg |
| Main circuit | |
| number of poles for main current circuit | 1 |
| number of NO contacts for main contacts | 1 |

| number of NC contacts for main contacts | 0 |
|---|--|
| number of NC contacts for main contacts | 0 |
| type of voltage of the operating voltage | AC |
| operating voltage | |
| at AC — at 50 Hz rated value | 48 460 V |
| | 48 460 V 48 460 V |
| — at 60 Hz rated value | |
| operating frequency rated value | 50 60 Hz |
| operating range relative to the operating voltage at AC | 40 500 14 |
| • at 50 Hz | 40 506 V |
| • at 60 Hz | 40 506 V |
| operational current | 20.4 |
| • at AC-51 rated value | 30 A |
| • at AC-51 according to IEC 60947-4-3 | 22 A |
| according to UL 508 rated value | 15 A |
| operational current minimum | 500 mA |
| rate of voltage rise at the thyristor for main contacts maximum permissible | 1 000 V/μs |
| blocking voltage at the thyristor for main contacts maximum permissible | 1 200 V |
| reverse current of the thyristor | 10 mA |
| derating temperature | 40 °C |
| surge current resistance rated value | 600 A |
| I2t value maximum | 1 800 A ² ·s |
| Control circuit/ Control | |
| type of voltage of the control supply voltage | DC |
| control supply voltage 1 at DC rated value maximum permissible | 30 V |
| control supply voltage 1 at DC | 15 24 V |
| control supply voltage | |
| at DC initial value for signal <1> detection | 15 V |
| at DC full-scale value for signal<0> recognition | 5 V |
| control current at minimum control supply voltage | |
| • at DC | 13 mA |
| control current at DC rated value | 15 mA |
| ON-delay time | 1 ms |
| OFF-delay time | 1 ms; additionally max. one half-wave |
| Auxiliary circuit | |
| type of switching contact | normally open contact (NO) |
| number of NC contacts for auxiliary contacts | 0 |
| number of NO contacts for auxiliary contacts | 0 |
| number of CO contacts for auxiliary contacts | 0 |
| Installation/ mounting/ dimensions | |
| fastening method side-by-side mounting | Yes |
| fastening method | screw fixing and snap-on mounting on standard mounting rail 35 mm according to IEC 60715 |
| design of the thread of the screw for securing the equipment | M4 |
| height | 100 mm |
| width | 45 mm |
| depth | 139 mm |
| Connections/ Terminals | |
| product component removable terminal for auxiliary and | Yes |
| control circuit | |
| type of electrical connection | |
| • for main current circuit | screw-type terminals |
| for auxiliary and control circuit | screw-type terminals |
| type of connectable conductor cross-sections | |
| • for main contacts | |
| — solid | 2x (1.5 2.5 mm²), 2x (2.5 6 mm²) |
| finely stranded with core end processing | 2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm² |
| • for AWG cables for main contacts | 2x (14 10) |
| connectable conductor cross-section for main contacts | |
| | |

| solid or stranded | 1.5 6 mm² |
|--|---|
| finely stranded with core end processing | 1 10 mm² |
| type of connectable conductor cross-sections | |
| for auxiliary and control contacts | |
| — solid | 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) |
| finely stranded with core end processing | 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) |
| — finely stranded without core end processing | 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) |
| for AWG cables for auxiliary and control contacts | 1x (AWG 20 12) |
| AWG number as coded connectable conductor cross section for main contacts | 10 14 |
| tightening torque | |
| for main contacts with screw-type terminals | 2 2.5 N·m |
| for auxiliary and control contacts with screw-type terminals | 0.5 0.6 N·m |
| tightening torque [lbf·in] | |
| for main contacts with screw-type terminals | 18 22 lbf-in |
| for auxiliary and control contacts with screw-type terminals | 4.5 5.3 lbf·in |
| design of the thread of the connection screw | |
| • for main contacts | M4 |
| of the auxiliary and control contacts | M3 |
| stripped length of the cable | 7 |
| • for main contacts | 7 mm |
| for auxiliary and control contacts Electrical Safety | 7 mm |
| Electrical Safety | IP20 |
| protection class IP on the front according to IEC 60529 touch protection on the front according to IEC 60529 | finger-safe, for vertical contact from the front |
| Ambient conditions | ingor-sais, for vertical contact from the front |
| installation altitude at height above sea level maximum | 1 000 m |
| ambient temperature | 1 000 111 |
| during operation | -25 +60 °C |
| during operation during storage | -55 +80 °C |
| Electromagnetic compatibility | |
| conducted interference | |
| due to burst according to IEC 61000-4-4 | 2 kV / 5 kHz behavior criterion 2 |
| due to conductor-earth surge according to IEC 61000-4-5 | 2 kV behavior criterion 2 |
| | |
| due to conductor-conductor surge according to IEC 61000-4-5 | 1 kV behavior criterion 2 |
| ů ů | 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 |
| 61000-4-5due to high-frequency radiation according to IEC 61000- | |
| 61000-4-5 ■ due to high-frequency radiation according to IEC 61000-4-6 | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 |
| 61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 |
| 61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 |
| 61000-4-5 ■ due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment |
| 61000-4-5 ■ due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment |
| 61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment |
| • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments |
| • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 |
| • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 |
| • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 |
| • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 |
| • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450 |
| • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450 |
| • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse | 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450 3NC2263 |

manufacturer's article number

- of DIAZED fuse usable
- of NEOZED fuse usable

<u>relays</u>

5SB2711; These fuses have a smaller rated current than the semiconductor relays

5SE2320: These fuses have a smaller rated current than the semiconductor relavs

Approvals Certificates

General Product Approval

EMV





Confirmation







Test Certificates

other

Railway

Environment

Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Special Test Certificate

Environmental Confirmations

Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2330-1BA04

Cax online generator

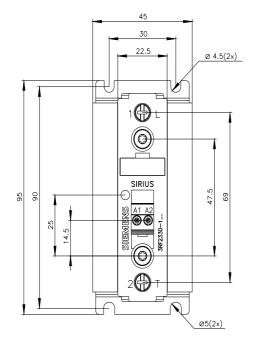
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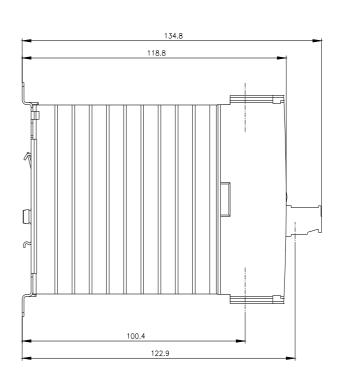
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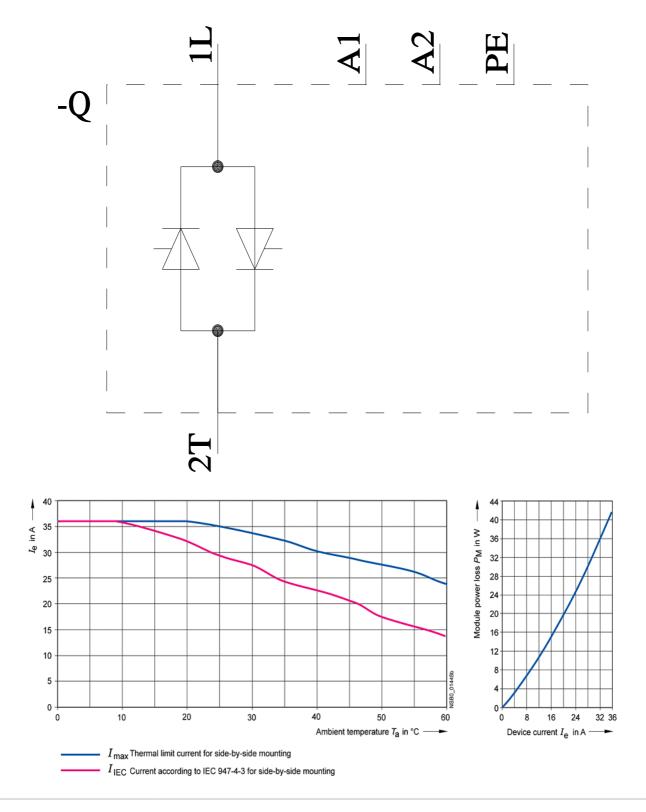
https://support.industry.siemens.com/cs/ww/en/ps/3RF2330-1BA04

 $Image\ database\ (product\ images,\ 2D\ dimension\ drawings,\ 3D\ models,\ device\ circuit\ diagrams,\ EPLAN\ macros,\ ...)$

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